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APPLICATION NO.	FIL	ING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	ATTORNEY DOCKET NO. CONFIRMATION NO.		
10/695,103	10/28/2003		Huey-Chiang Liou	ITL.1054US (P17790)	4735		
21906	7590	08/20/2004		EXAM	EXAMINER		
TROP PRU 8554 KATY		•	DANG, T	DANG, TRUNG Q			
SUITE 100	IKEEWA	•		ART UNIT	PAPER NUMBER		
HOUSTON,	TX 7702	4	2823				

DATE MAILED: 08/20/2004

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	. Applicant(s)	
Office Action Summany	10/695,103	LIOU ET AL.	
Office Action Summary	Examiner	Art Unit	ر _
	Trung Dang	2823	1 1 1 1 1 1 1 1 1 1
The MAILING DATE of this communication app Period for Reply	ears on the cover sheet with the c	correspondence ac	ddress
A SHORTENED STATUTORY PERIOD FOR REPLY THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.13 after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a reply If NO period for reply is specified above, the maximum statutory period w. - Failure to reply within the set or extended period for reply will, by statute, Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	within the statutory minimum of thirty (30) day ill apply and will expire SIX (6) MONTHS from cause the application to become ABANDONE	nely filed s will be considered time the mailing date of this of D (35 U.S.C. § 133).	
Status			
1) Responsive to communication(s) filed on			
	action is non-final.		
3) Since this application is in condition for allowan	ce except for formal matters, pro	secution as to the	e merits is
closed in accordance with the practice under E	x parte Quayle, 1935 C.D. 11, 45	53 O.G. 213.	
Disposition of Claims			
4)⊠ Claim(s) <u>1-15</u> is/are pending in the application.			
4a) Of the above claim(s) is/are withdraw	vn from consideration.		
5) Claim(s) is/are allowed.			
6)⊠ Claim(s) 1-15 is/are rejected.			
7) Claim(s) is/are objected to.			
8) Claim(s) are subject to restriction and/or	election requirement.		
Application Papers			
9) The specification is objected to by the Examine	г.		
10) The drawing(s) filed on is/are: a) acce		Examiner.	
Applicant may not request that any objection to the	drawing(s) be held in abeyance. See	e 37 CFR 1.85(a).	
Replacement drawing sheet(s) including the correcti	on is required if the drawing(s) is ob	jected to. See 37 C	FR 1.121(d).
11) The oath or declaration is objected to by the Ex	aminer. Note the attached Office	Action or form P	TO-152.
Priority under 35 U.S.C. § 119			
12) Acknowledgment is made of a claim for foreign a) All b) Some * c) None of:)-(d) or (f).	
1. Certified copies of the priority documents		NI-	
2. Certified copies of the priority documents3. Copies of the certified copies of the prior			Stage
 Copies of the certified copies of the prior application from the International Bureau 	•	eu iii tiiis Nationa	Stage
* See the attached detailed Office action for a list of		ed.	
COS AND GREENING GOLGHOU GORGIT FOR A HIGH	2 33 34 35 p. 33 mor 1030 p. 103		
Attachmont/ol			
Attachment(s) 1) X Notice of References Cited (PTO-892)	4) Interview Summary	(PTO-413)	
2) Notice of Praftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08) Paper No(s)/Mail Date	Paper No(s)/Mail Da 5) Notice of Informal F 6) Other:	ate	O-152)
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DETAILED ACTION

Claim Rejections - 35 USC § 103

- 1. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 2. Claims 1-15 are rejected under 35 U.S.C. 103(a) as being unpatentable over Trefonas, III (U.S. Pat. 6,280,911) in view of Morita et al. (U.S. Pat. 5,185,296).

For method claims 7-12, Trefonas teaches a method comprising: forming a chemically amplified photoresist over a semiconductor substrate by blending at least one non-ionic photoacid generator (PGA) in photoresist compositions (col. 1, lines 59-63; col. 14, lines 1-3). Note that, a photoresist when incorporated a PGA is called a chemically amplified photoresist.

Trefonas differs from the claims in not specifically discloses that the chemically amplified photoresist is coated over the semiconductor substrate by Langmuir-Blodgett (LB) method even though Trefonas suggests that the photoresist may be applied by any standard means including dipping or spinning (col.14, lines 9-11).

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Morita et al. teach a method in which a photoresist layer is coated on a semiconductor substrate by known techniques including spin coating and LB method (col. 5, lines 50-55).

The subject matter as a whole would have been obvious to one of ordinary skill in the art to coat the photoresist of Trefonas by LB method because the substitution of art recognized equivalents as taught by Morita et al. would have been within the level of one skilled in the art. Furthermore, it is known in the art that a photoresist layer coated by LB method would have the benefit of producing a fine pattern because of the order orientation of molecules of the LB film. Note that LB method involves dipping process to form a film on a substrate.

For claim 9, see Trefonas reference, col. 4, line 55 for the chemical formula of the non-ionic PAG where XaR is -CF3 (col.4, line 63, n=1) and X, Y form a fused aromatic ring (col. 5, line 3).

For claim 10, see Trefonas reference, col. 4, line 30 for the chemical formula of the non-ionic PAG.

For claims 11-12, see Trefonas' abstract.

With respect to product claims 1-6 and 13-15, the structure as claimed is obtained by the combined process as noted above.

For claim 13, it is noted that PAG contained in the exposed portion of the resist generates an acid (hydrogen ion) that functions as a catalyst at the time of baking to start a cross linking reaction (in the case of a negative photoresist) or to

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reduce the dissolution inhibiting effect (in the case of a positive photoresist), hence the polymer in Trefonas' photoresist is an acid sensitive polymer because the acid causes chemical reactions in the polymer as explained above.

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- 3. Applicants are requested to provide references cited in pages 7 and 8 of the present specification because these references are non-patent literatures that are not readily obtainable by the Examiner.
- 4. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Trung Dang whose telephone number is 571-272-1857. The examiner can normally be reached on Mon-Friday 9:30am-6:00pm.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Olik Chaudhuri can be reached on 571-272-1855. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov.

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Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Trung Dang Primary Examiner Art Unit 2823

August 09, 2004

Aung Dang